Product Name : F.E.T. Characteristics

Product Code : NLAB-ELECTRONICSAB420010

Description:

F.E.T. Characteristics

Technical Specification :

Experimental Training Board has been designed specifically to study the characteristics of a Field Effect Transistor. The board is absolutely self

contained and requires no other apparatus.

Practical experience on this board carries great educative value for Science and Engineering Students.

Object:

To study the characteristics of Field Effect Transistor.

1. Measurement of IDSS

- 2. Plot the static drain characteristics of FET
- 2.1 Drain Current V/s Drain Voltage Characteristics for different fixed values of VGS
- 2.2 Drain Current V/s Gate Bias Characteristics for different fixed values of VDS
- 3. Show that FET work as VVR (voltage variable resistance).

4. Calculate the FET parameters (drain dynamic resistance r , mutual conductance g , and amplification factor m) at a given operating point.

FEATURES

The Board consists of the following built-in parts:

- 1. 0 to 20V D.C. at 50mA, continuously variable Power Supply.
- 2. 0 to 12V D.C. at 50mA, continuously variable Power Supply.
- 3. Two Digital Voltmeter DC 31/2 Digit having range of 0- 20V.
- 4. Digital Current meter DC 31/2 Digit having range of 0- 20mA
- 5. One Field Effect Transistor.
- 6. Adequate no. of other electronic components.
- 7. Mains ON/OFF switch, Fuse and Jewel light.
- 8. The unit is operative on 230V $\pm 10\%$ at 50Hz A.C. Mains.
- 9. Adequate no. of patch cords 4mm length 50cm.

Weight : 3 Kg. (Approx.)

Dimension : W 340 x H 110 x D 210

Naugralabequipments

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